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# Product Change Notification



Product Group: OPT/Mon Mar 20, 2023/PCN-OPT-1233-2022-REV-0

## Changes of materials for TFBS4xxx IRDC Product Series

For further information, please contact your regional Vishay office.

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**Description of Change:** -Introduction of a new in-house designed IRDC IC. The Chaldene IC provides 20 percent longer distance (in meters) and improved ESD robustness from current 1kV to 2kV.

-Introduction of a new Surface Emitting Technology Chip.

-Changeover of the Au wire Diameter from 30um to 25um.

We recommend to test the product in customers application.

**Classification of Change:** - New IC:

The existing external IC Supplier will end the production. In order to assure a long-term product availability of IRDC products, Vishay developed an inhouse IC in cooperation with the worlds leading Chip Foundry.

-New Emitter Chip:

Changeover to latest Surface Emitting Technology to assure long-term product availability.

-Au wire Diameter reduction:

In order to streamline the production and optimize the material supply chain, Vishay introduces a new Standardization of Au wire Diameter.

The material is qualified to high Standards.

**Expected Influence on Quality/Reliability/Performance:** No change on Quality/Reliability. Similar electrical and optical characteristics.

**Part Numbers/Series/Families Affected:** Please see materials list on the succeeding page.

**Vishay Brand(S):** Vishay Semiconductors

**Time Schedule:**

Start Shipment Date: Mon Jan 1, 2024

**Sample Availability:** Samples are available ww13 2023.



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**Product Group:** OPT/Mon Mar 20, 2023/PCN-OPT-1233-2022-REV-0

**Product Identification:** via date code

**Qualification Data:** Qual pack is available

**This PCN is considered approved, without further notification, unless we receive specific customer concerns before Sun Apr 30, 2023 or as specified by contract.**

**Issued By:** Rainer Hauschildt, [rainer.hauschildt@vishay.com](mailto:rainer.hauschildt@vishay.com)



# Product Change Notification



Product Group: OPT/Mon Mar 20, 2023/PCN-OPT-1233-2022-REV-0

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|               |               |               |               |               |
|---------------|---------------|---------------|---------------|---------------|
| TFBS4650E-TR1 | TFBS4650E-TR3 | TFBS4650E-TR3 | TFBS4650E-TT1 | TFBS4650E-TT3 |
| TFBS4650-TR1  | TFBS4650-TR3  | TFBS4650-TR4  | TFBS4650-TT3  | TFBS4652E-TR1 |
| TFBS4652E-TR3 | TFBS4652E-TT1 | TFBS4652E-TT3 | TFBS4652K-TT1 | TFBS4652-TR1  |
| TFBS4652-TR3  | TFBS4652-TT1  | TFBS4711D-TT1 | TFBS4711E-TR1 | TFBS4711E-TR3 |
| TFBS4711E-TT1 | TFBS4711E-TT3 | TFBS4711H-TR1 | TFBS4711-TR1  | TFBS4711-TR3  |
| TFBS4711-TT1  |               |               |               |               |



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## Changes of materials for TFBS4xxx IRDC Series

Vishay Opto has published a PCN announcing materials changes for the IRDC Transceiver products:

-Introduction of a new in-house designed IRDC IC. The Chaldene IC provides 20 percent longer distance (in meters) and improved ESD robustness from current 1kV to 2kV.

-Introduction of a new Surface Emitting Technology Chip.

-Changeover of the Au wire Diameter from 30um to 25um.

We recommend to order samples and test the products in customers application.

FAQ:

Q: Are there any technical differences (form/fit/function) expected?

A: Mechanically there are no changes.

Electrically/Optically the performance of the Transmitter changes in the following way:

### TFBS465x

#### Before PCN:

| TRANSMITTER                                |  |                        |      |         |      |                                |
|--|--|------------------------|------|---------|------|--------------------------------|
| IREC operating current, current controlled | The IREC current is internally controlled but also can be reduced by an external resistor R1   | $I_D$                  | 200  | 300     | 400  | mA                             |
| Forward voltage of built-in IREC           | $I_F = 300 \text{ mA}$   | $V_F$                  | 1.4  | 1.8     | 1.9  | V                              |
| Output leakage IREC current                | $T_{amb} = 85^\circ \text{C}$  | $I_{IREC}$             | -    | -       | 1    | $\mu\text{A}$                  |
| Output radiant intensity <sup>(5)</sup>    | $a = 0^\circ, 15^\circ, \text{TXD} = \text{high}, \text{SD} = \text{low}, V_{OC1} = 3 \text{ V}, V_{OC2} = 3 \text{ V}, R1 = 30 \Omega$ (resulting in about 50 mA drive current) | $I_e$                  | 5    | 10      | 25   | mW/sr                          |
| Output radiant intensity <sup>(5)</sup>    | $a = 0^\circ, 15^\circ, \text{TXD} = \text{high}, \text{SD} = \text{low}, V_{OC1} = 3 \text{ V}, V_{OC2} = 3 \text{ V}, R1 = 0 \Omega, I_F = 300 \text{ mA}$                     | $I_e$                  | 30   | 65      | 150  | mW/sr                          |
| Output radiant intensity <sup>(5)</sup>    | $V_{OC1} = 5 \text{ V}, a = 0^\circ, 15^\circ, \text{TXD} = \text{low or SD} = \text{high}$ (receiver is inactive as long as SD = high)  | $I_e$                  | -    | -       | 0.04 | mW/sr                          |
| Saturation voltage of IREC driver          | $V_{CC} = 3 \text{ V}, I_F = 50 \text{ mA}$  | $V_{CEsat}$            | -    | 0.4     | -    | V                              |
| Peak - emission wavelength                 |  | $\lambda_p$            | 880  | 886     | 900  | nm                             |
| Spectral bandwidth                         |  | $\Delta\lambda$        | -    | 45      | -    | nm                             |
| Optical rise time, optical fall time       |  | $t_{ropt}, t_{fopt}$   | 20   | -       | 100  | ns                             |
| Optical output pulse duration              | Input pulse width $t < 30 \mu\text{s}$<br>Input pulse width $t \geq 30 \mu\text{s}$  | $t_{opt}$<br>$t_{opt}$ | 30   | t<br>50 | 300  | $\mu\text{s}$<br>$\mu\text{s}$ |
| Optical output pulse duration              | Input pulse width $t = 1.63 \mu\text{s}$   | $t_{opt}$              | 1.45 | 1.61    | 2.2  | $\mu\text{s}$                  |
| Optical overshoot                          |  |                        | -    | -       | 20   | %                              |

**After Surface Emitter implementation:**

| TRANSMITTER (new surface emitter values introduced via PCN) |   |                                       |                         |      |                         |       |
|---|---|---------------------------------------|-------------------------|------|-------------------------|-------|
| IRET operating current limitation                           | No external resistor for current limitation <sup>(4)</sup>  | I <sub>D</sub>                        | 200                     | 300  | 430                     | mA    |
| Forward voltage of built-in IRED                            | I <sub>F</sub> = 300 mA   | V <sub>F</sub>                        | 1.4                     | 1.8  | 1.9                     | V     |
| Output leakage IRED current                                 | TXD = 0 V, 0 < V <sub>CC1</sub> < 5.5 V   | I <sub>IRET</sub>                     | -1                      | 0.01 | 1                       | μA    |
| Output radiant intensity                                    | α = 0°, 15°, TXD = high, SD = low   | I <sub>e</sub>                        | 40                      | 250  | 400                     | mW/sr |
|   | V <sub>CC1</sub> = 5 V, α = 0°, 15°, TXD = low or SD = high (receiver is inactive as long as SD = high) | I <sub>e</sub>                        | -                       | -    | 0.04                    | mW/sr |
| Output radiant intensity, angle of half intensity           |   | α                                     | -                       | ± 30 | -                       | °     |
| Peak - emission wavelength <sup>(5)</sup>                   |   | λ <sub>p</sub>                        | 870                     | -    | 910                     | nm    |
| Spectral bandwidth  |   | Δλ                                    | -                       | 45   | -                       | nm    |
| Optical rise time, fall time                                |   | t <sub>ropt</sub> , t <sub>fopt</sub> | 10                      | 50   | 300                     | ns    |
| Optical output pulse duration                               | Input pulse width 1.6 < t <sub>TXD</sub> < 23 μs  | t <sub>opt</sub>                      | t <sub>TXD</sub> - 0.15 | -    | t <sub>TXD</sub> + 0.15 | μs    |
|   | Input pulse width t <sub>TXD</sub> ≥ 23 μs  | t <sub>opt</sub>                      | 23                      | 50   | 100                     | μs    |
| Optical overshoot   |   |                                       | -                       | -    | 25                      | %     |

**TFBS4711xx****Before PCN:**

| TRANSMITTER (new surface emitter values introduced via PCN) |   |                   |                         |      |                         |       |
|---|---|-------------------|-------------------------|------|-------------------------|-------|
| IRET operating current limitation                           | No external resistor for current limitation <sup>(5)</sup>  | I <sub>D</sub>    | 200                     | 300  | 430                     | mA    |
| Forward voltage of built-in IRED                            | I <sub>F</sub> = 300 mA   | V <sub>F</sub>    | 1.4                     | 1.8  | 1.9                     | V     |
| Output leakage IRED current                                 | TXD = 0 V, 0 < V <sub>CC1</sub> < 5.5 V   | I <sub>IRET</sub> | -1                      | 0.01 | 1                       | μA    |
| Output radiant intensity                                    | α = 0°, 15°<br>TXD = high, SD = low   | I <sub>e</sub>    | 40                      | 140  | 300                     | mW/sr |
|   | V <sub>CC1</sub> = 5 V, α = 0°, 15°, TXD = low or SD = high (receiver is inactive as long as SD = high) | I <sub>e</sub>    | -                       | -    | 0.04                    | mW/sr |
| Output radiant intensity, angle of half intensity           |   | α                 | -                       | ± 24 | -                       | deg   |
| Peak-emission wavelength <sup>(6)</sup>                     |   | λ <sub>p</sub>    | 870                     | -    | 910                     | nm    |
| Spectral bandwidth  |   | Δλ                | -                       | 45   | -                       | nm    |
| Optical rise time   |   | t <sub>ropt</sub> | 10                      | 50   | 300                     | ns    |
| Optical fall time   |   | t <sub>fopt</sub> | 10                      | 50   | 300                     | ns    |
| Optical output pulse duration                               | Input pulse width 1.6 < t <sub>TXD</sub> < 23 μs  | t <sub>opt</sub>  | t <sub>TXD</sub> - 0.15 | -    | t <sub>TXD</sub> + 0.15 | μs    |
|   | Input pulse width t <sub>TXD</sub> ≥ 23 μs  | t <sub>opt</sub>  | 23                      | 50   | 100                     | μs    |
| Optical overshoot   |   |                   | -                       | -    | 25                      | %     |

**After Surface Emitter implementation:**

| OPTOELECTRONIC CHARACTERISTICS (T <sub>amb</sub> = 25 °C, V <sub>CC1</sub> = V <sub>CC2</sub> = 2.4 V to 5.5 V unless otherwise noted) |   |                   |                         |      |                         |       |
|--|---|-------------------|-------------------------|------|-------------------------|-------|
| PARAMETER  | TEST CONDITIONS   | SYMBOL            | MIN.                    | TYP. | MAX.                    | UNIT  |
| TRANSMITTER  |   |                   |                         |      |                         |       |
| IRET operating current limitation  | No external resistor for current limitation <sup>(5)</sup>  | I <sub>D</sub>    | 200                     | 300  | 430                     | mA    |
| Forward voltage of built-in IRED   | I <sub>F</sub> = 300 mA   | V <sub>F</sub>    | 1.4                     | 1.8  | 1.9                     | V     |
| Output leakage IRED current  | TXD = 0 V, 0 < V <sub>CC1</sub> < 5.5 V   | I <sub>IRET</sub> | -1                      | 0.01 | 1                       | μA    |
| Output radiant intensity   | α = 0°, 15°<br>TXD = high, SD = low   | I <sub>e</sub>    | 40                      | 140  | 300                     | mW/sr |
|  | V <sub>CC1</sub> = 5 V, α = 0°, 15°, TXD = low or SD = high (receiver is inactive as long as SD = high) | I <sub>e</sub>    | -                       | -    | 0.04                    | mW/sr |
| Output radiant intensity, angle of half intensity  |   | α                 | -                       | ± 24 | -                       | deg   |
| Peak-emission wavelength <sup>(6)</sup>  |   | λ <sub>p</sub>    | 870                     | -    | 910                     | nm    |
| Spectral bandwidth   |   | Δλ                | -                       | 45   | -                       | nm    |
| Optical rise time  |   | t <sub>ropt</sub> | 10                      | 50   | 300                     | ns    |
| Optical fall time  |   | t <sub>fopt</sub> | 10                      | 50   | 300                     | ns    |
| Optical output pulse duration  | Input pulse width 1.6 < t <sub>TXD</sub> < 23 μs  | t <sub>opt</sub>  | t <sub>TXD</sub> - 0.15 | -    | t <sub>TXD</sub> + 0.15 | μs    |
|  | Input pulse width t <sub>TXD</sub> ≥ 23 μs  | t <sub>opt</sub>  | 23                      | 50   | 100                     | μs    |
| Optical overshoot  |   |                   | -                       | -    | 25                      | %     |

For all details, please check the latest datasheet on [www.vishay.com](http://www.vishay.com).

Q: When do we plan to implement the new materials in production?

A: In Vishay production work week **1 2024**.



## FAST FACTS



Product Group: Vishay Opto / Mar 2023

Q: How can the customer distinguish products including these changes?

A: The PCN announces a changeover date (production work week). The standard bar code label contains the production week as shown below (Batch 202222PH19 produced in ww22 2022). A green sticker will be added to the box label for shipments which include the changes:



Q: Why has Vishay introduced these changes?

A: - New IC:

The existing external IC Supplier will end the production. In order to assure a long-term product availability of IRDC products, Vishay developed an inhouse IC in cooperation with the worlds leading Chip Foundry.

-New Emitter Chip:

Changeover to latest Surface Emitting Technology to assure long-term product availability.

-Au wire Diameter reduction:

In order to streamline the production and optimize the material supply chain, Vishay introduces a new Standardization of Au wire Diameter. The material is qualified to high Standards.

Q: Are datasheets available?

A: Yes. The updated datasheets are available on our website 27th Mar 2023. The header will state that the datasheet content is in accordance with this PCN.

Q: Are samples of TFBS4xxx Series available?

A: Yes, samples can be ordered by contacting me or our Regional Marketing colleagues.

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| Vishay Material Code | Customer Material | Location |
|----------------------|-------------------|----------|
| TFBS4650-TR1         | TFBS4650-TR1      | CHANDLER |
| TFBS4711-TR1         |                   | Chandler |
| TFBS4711-TR1         | 136079-L3         | CHANDLER |
| TFBS4711-TR1         | TFBS4711-TR1      | CHANDLER |
| TFBS4711-TR3         | TFBS4711-TR3      | CHANDLER |
| TFBS4711-TT1         |                   | Chandler |
| TFBS4711-TT1         | 136078-L3         | CHANDLER |
| TFBS4711-TT1         | TFBS4711-TT1      | CHANDLER |